

# 74LVC3G14

## Triple inverting Schmitt trigger with 5 V tolerant input

Rev. 07 — 12 June 2008

Product data sheet

### 1. General description

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The 74LVC3G14 provides three inverting buffers with Schmitt trigger action.

The inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment. Schmitt trigger action at the inputs makes the circuit tolerant of slower input rise and fall time. This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features

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- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Unlimited rise and fall times
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  $-40$  °C to  $+125$  °C.

### 3. Applications

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- Wave and pulse shaper for highly noisy environment
- Astable multivibrator
- Monostable multivibrator.

4. Ordering information

Table 1. Ordering information

| Type number | Package           |        |                                                                                                      |          |
|-------------|-------------------|--------|------------------------------------------------------------------------------------------------------|----------|
|             | Temperature range | Name   | Description                                                                                          | Version  |
| 74LVC3G14DP | −40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm              | SOT505-2 |
| 74LVC3G14DC | −40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm                           | SOT765-1 |
| 74LVC3G14GT | −40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm          | SOT833-1 |
| 74LVC3G14GD | −40 °C to +125 °C | XSON8U | plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body 3 × 2 × 0.5 mm | SOT996-2 |
| 74LVC3G14GM | −40 °C to +125 °C | XQFN8U | plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body 1.6 × 1.6 × 0.5 mm | SOT902-1 |

5. Marking

Table 2. Marking codes

| Type number | Marking code |
|-------------|--------------|
| 74LVC3G14DP | V14          |
| 74LVC3G14DC | V14          |
| 74LVC3G14GT | V14          |
| 74LVC3G14GD | V14          |
| 74LVC3G14GM | V14          |

6. Functional diagram

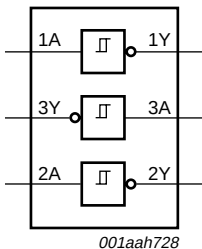


Fig 1. Logic symbol

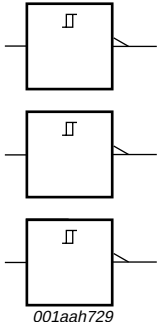


Fig 2. IEC logic symbol

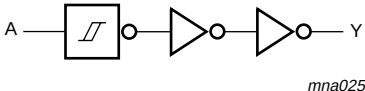
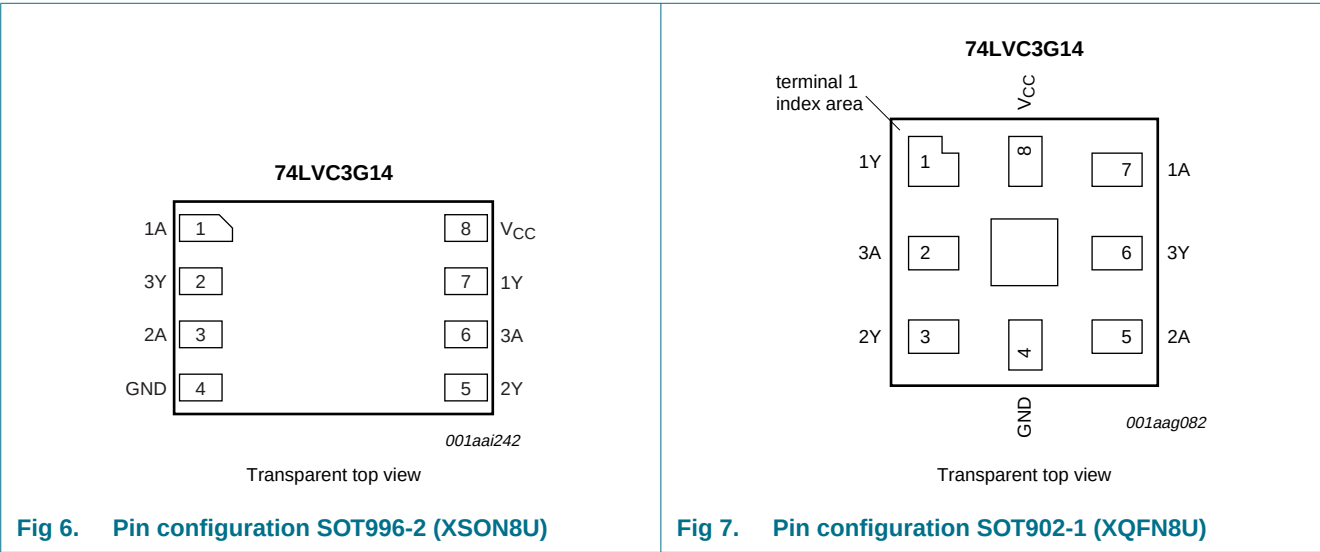
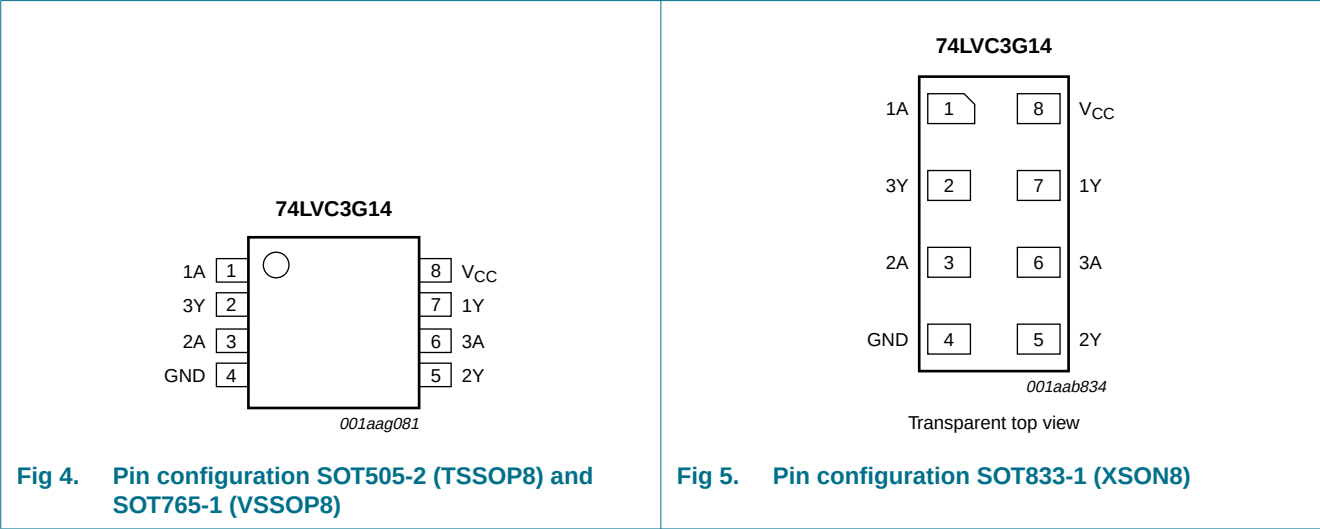


Fig 3. Logic diagram (one Schmitt trigger)

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

| Symbol     | Pin                                       |          | Description    |
|------------|-------------------------------------------|----------|----------------|
|            | SOT505-2, SOT765-1, SOT833-1 and SOT996-2 | SOT902-1 |                |
| 1A, 2A, 3A | 1, 3, 6                                   | 7, 5, 2  | data input     |
| 1Y, 2Y, 3Y | 7, 5, 2                                   | 1, 3, 6  | data output    |
| GND        | 4                                         | 4        | ground (0 V)   |
| VCC        | 8                                         | 8        | supply voltage |

## 8. Functional description

Table 4. Function table [\[1\]](#)

| Input nA | Output nY |
|----------|-----------|
| L        | H         |
| H        | L         |

[1] H = HIGH voltage level; L = LOW voltage level

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                    | Min                         | Max            | Unit |
|-----------|-------------------------|-------------------------------|-----------------------------|----------------|------|
| $V_{CC}$  | supply voltage          |                               | -0.5                        | +6.5           | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                   | -50                         | -              | mA   |
| $V_I$     | input voltage           |                               | <a href="#">[1]</a> -0.5    | +6.5           | V    |
| $I_{OK}$  | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V | -                           | ±50            | mA   |
| $V_O$     | output voltage          | Active mode                   | <a href="#">[1][2]</a> -0.5 | $V_{CC} + 0.5$ | V    |
|           |                         | Power-down mode               | <a href="#">[1][2]</a> -0.5 | +6.5           | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$       | -                           | ±50            | mA   |
| $I_{CC}$  | supply current          |                               | -                           | 100            | mA   |
| $I_{GND}$ | ground current          |                               | -100                        | -              | mA   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C | <a href="#">[3]</a> -       | 250            | mW   |
| $T_{stg}$ | storage temperature     |                               | -65                         | +150           | °C   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When  $V_{CC} = 0$  V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP8 package: above 55 °C the value of  $P_{tot}$  derates linearly with 2.5 mW/K.

For VSSOP8 package: above 110 °C the value of  $P_{tot}$  derates linearly with 8 mW/K.

For XSON8, XSON8U and XQFN8U packages: above 45 °C the value of  $P_{tot}$  derates linearly with 2.4 mW/K.

## 10. Recommended operating conditions

Table 6. Operating conditions

| Symbol    | Parameter           | Conditions                      | Min  | Max      | Unit |
|-----------|---------------------|---------------------------------|------|----------|------|
| $V_{CC}$  | supply voltage      |                                 | 1.65 | 5.5      | V    |
| $V_I$     | input voltage       |                                 | 0    | 5.5      | V    |
| $V_O$     | output voltage      | Active mode                     | 0    | $V_{CC}$ | V    |
|           |                     | Power-down mode; $V_{CC} = 0$ V | 0    | 5.5      | V    |
| $T_{amb}$ | ambient temperature |                                 | -40  | +125     | °C   |

## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                 | Conditions                                                                                          | Min                   | Typ <sup>[1]</sup> | Max  | Unit |
|--------------------------------------------|---------------------------|-----------------------------------------------------------------------------------------------------|-----------------------|--------------------|------|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b>  |                           |                                                                                                     |                       |                    |      |      |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = -100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                         | V <sub>CC</sub> - 0.1 | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V                                                    | 1.2                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V                                                     | 1.9                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V                                                    | 2.2                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V                                                    | 2.3                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V                                                    | 3.8                   | -                  | -    | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                          | -                     | -                  | 0.1  | V    |
|                                            |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V                                                     | -                     | -                  | 0.45 | V    |
|                                            |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V                                                      | -                     | -                  | 0.3  | V    |
|                                            |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                                                     | -                     | -                  | 0.4  | V    |
|                                            |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V                                                     | -                     | -                  | 0.55 | V    |
|                                            |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V                                                     | -                     | -                  | 0.55 | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V                                       | -                     | ±0.1               | ±5   | µA   |
| I <sub>OFF</sub>                           | power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V                                     | -                     | ±0.1               | ±10  | µA   |
| I <sub>CC</sub>                            | supply current            | V <sub>I</sub> = 5.5 V or GND; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 1.65 V to 5.5 V           | -                     | 0.1                | 10   | µA   |
| ΔI <sub>CC</sub>                           | additional supply current | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 2.3 V to 5.5 V | -                     | 5                  | 500  | µA   |
| C <sub>I</sub>                             | input capacitance         | V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = GND to V <sub>CC</sub>                                    | -                     | 3.5                | -    | pF   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                           |                                                                                                     |                       |                    |      |      |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = -100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                         | V <sub>CC</sub> - 0.1 | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V                                                    | 0.95                  | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V                                                     | 1.7                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V                                                    | 1.9                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V                                                    | 2.0                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V                                                    | 3.4                   | -                  | -    | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                          | -                     | -                  | 0.1  | V    |
|                                            |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V                                                     | -                     | -                  | 0.7  | V    |
|                                            |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V                                                      | -                     | -                  | 0.45 | V    |
|                                            |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                                                     | -                     | -                  | 0.6  | V    |
|                                            |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V                                                     | -                     | -                  | 0.8  | V    |
|                                            |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V                                                     | -                     | -                  | 0.8  | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V                                       | -                     | -                  | ±20  | µA   |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                 | Conditions                                                        | Min | Typ <sup>[1]</sup> | Max      | Unit    |
|-----------------|---------------------------|-------------------------------------------------------------------|-----|--------------------|----------|---------|
| $I_{OFF}$       | power-off leakage current | $V_I$ or $V_O = 5.5$ V; $V_{CC} = 0$ V                            | -   | -                  | $\pm 20$ | $\mu$ A |
| $I_{CC}$        | supply current            | $V_I = 5.5$ V or GND; $I_O = 0$ A;<br>$V_{CC} = 1.65$ V to 5.5 V  | -   | -                  | 40       | $\mu$ A |
| $\Delta I_{CC}$ | additional supply current | $V_I = V_{CC} - 0.6$ V; $I_O = 0$ A;<br>$V_{CC} = 2.3$ V to 5.5 V | -   | -                  | 5000     | $\mu$ A |

[1] All typical values are measured at maximum  $V_{CC}$  and  $T_{amb} = 25$  °C.**Table 8.** Transfer characteristicsVoltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#))

| Symbol               | Parameter                        | Conditions                                                                              | -40 °C to +85 °C |                    |      | -40 °C to +125 °C |      | Unit |
|----------------------|----------------------------------|-----------------------------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|                      |                                  |                                                                                         | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| $V_{T+}$             | positive-going threshold voltage | see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>                             |                  |                    |      |                   |      |      |
|                      |                                  | $V_{CC} = 1.8$ V                                                                        | 0.70             | 1.10               | 1.50 | 0.70              | 1.70 | V    |
|                      |                                  | $V_{CC} = 2.3$ V                                                                        | 1.00             | 1.40               | 1.80 | 1.00              | 2.00 | V    |
|                      |                                  | $V_{CC} = 3.0$ V                                                                        | 1.30             | 1.76               | 2.20 | 1.30              | 2.40 | V    |
|                      |                                  | $V_{CC} = 4.5$ V                                                                        | 1.90             | 2.47               | 3.10 | 1.90              | 3.30 | V    |
|                      |                                  | $V_{CC} = 5.5$ V                                                                        | 2.20             | 2.91               | 3.60 | 2.20              | 3.80 | V    |
| $V_{T-}$             | negative-going threshold voltage | see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>                             |                  |                    |      |                   |      |      |
|                      |                                  | $V_{CC} = 1.8$ V                                                                        | 0.25             | 0.61               | 0.90 | 0.25              | 1.10 | V    |
|                      |                                  | $V_{CC} = 2.3$ V                                                                        | 0.40             | 0.80               | 1.15 | 0.40              | 1.35 | V    |
|                      |                                  | $V_{CC} = 3.0$ V                                                                        | 0.60             | 1.04               | 1.50 | 0.60              | 1.70 | V    |
|                      |                                  | $V_{CC} = 4.5$ V                                                                        | 1.00             | 1.55               | 2.00 | 1.00              | 2.20 | V    |
|                      |                                  | $V_{CC} = 5.5$ V                                                                        | 1.20             | 1.86               | 2.30 | 1.20              | 2.50 | V    |
| $V_H$ <sup>[2]</sup> | hysteresis voltage               | see <a href="#">Figure 10</a> , <a href="#">Figure 11</a> and <a href="#">Figure 12</a> |                  |                    |      |                   |      |      |
|                      |                                  | $V_{CC} = 1.8$ V                                                                        | 0.15             | 0.49               | 1.00 | 0.15              | 1.20 | V    |
|                      |                                  | $V_{CC} = 2.3$ V                                                                        | 0.25             | 0.60               | 1.10 | 0.25              | 1.30 | V    |
|                      |                                  | $V_{CC} = 3.0$ V                                                                        | 0.40             | 0.73               | 1.20 | 0.40              | 1.40 | V    |
|                      |                                  | $V_{CC} = 4.5$ V                                                                        | 0.60             | 0.92               | 1.50 | 0.60              | 1.70 | V    |
|                      |                                  | $V_{CC} = 5.5$ V                                                                        | 0.70             | 1.02               | 1.70 | 0.70              | 1.90 | V    |

[1] All typical values are measured at  $T_{amb} = 25$  °C[2]  $V_H = V_{T+} - V_{T-}$

## 12. Dynamic characteristics

**Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 9](#).

| Symbol   | Parameter                     | Conditions                                                           | –40 °C to +85 °C |                    |      | –40 °C to +125 °C |      | Unit |
|----------|-------------------------------|----------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|          |                               |                                                                      | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| $t_{pd}$ | propagation delay             | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup>                |                  |                    |      |                   |      |      |
|          |                               | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$                         | 1.0              | 4.2                | 11.0 | 1.0               | 12.0 | ns   |
|          |                               | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$                           | 0.5              | 3.0                | 6.5  | 0.5               | 7.2  | ns   |
|          |                               | $V_{CC} = 2.7 \text{ V}$                                             | 0.5              | 3.8                | 7.0  | 0.5               | 7.7  | ns   |
|          |                               | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$                           | 0.5              | 3.2                | 6.0  | 0.5               | 6.7  | ns   |
|          |                               | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$                           | 0.5              | 2.4                | 4.3  | 0.5               | 4.7  | ns   |
| $C_{PD}$ | power dissipation capacitance | $V_I = \text{GND to } V_{CC}; V_{CC} = 3.3 \text{ V}$ <sup>[3]</sup> | -                | 18.1               | -    | -                 | -    | pF   |

[1] Typical values are measured at  $T_{amb} = 25 \text{ °C}$  and  $V_{CC} = 1.8 \text{ V}, 2.5 \text{ V}, 2.7 \text{ V}, 3.3 \text{ V}$  and  $5.0 \text{ V}$  respectively.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

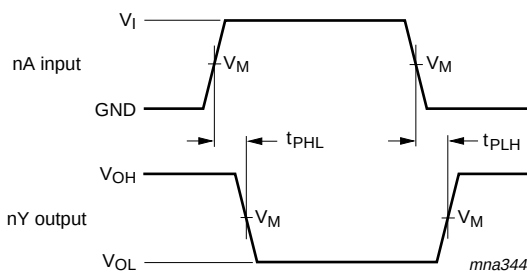
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 13. Waveforms



Measurement points are given in [Table 10](#).  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 8. The data input (nA) to output (nY) propagation delays**

Table 10. Measurement points

| V <sub>CC</sub>  | Input V <sub>M</sub>  | Output V <sub>M</sub> |
|------------------|-----------------------|-----------------------|
| 1.65 V to 1.95 V | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.3 V to 2.7 V   | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.7 V            | 1.5 V                 | 1.5 V                 |
| 3.0 V to 3.6 V   | 1.5 V                 | 1.5 V                 |
| 4.5 V to 5.5 V   | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |

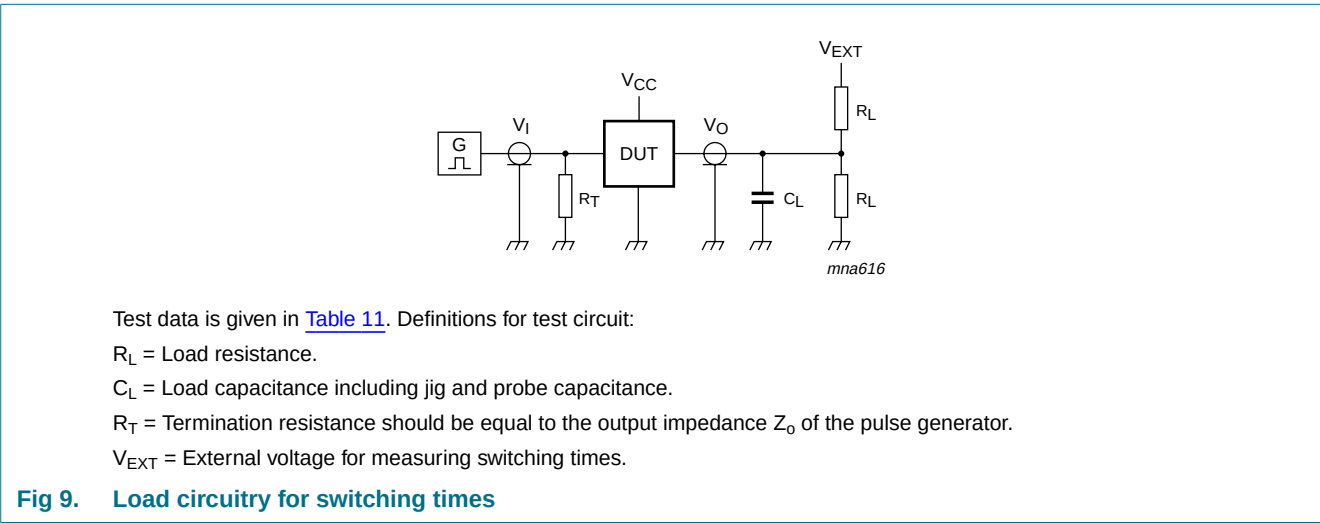
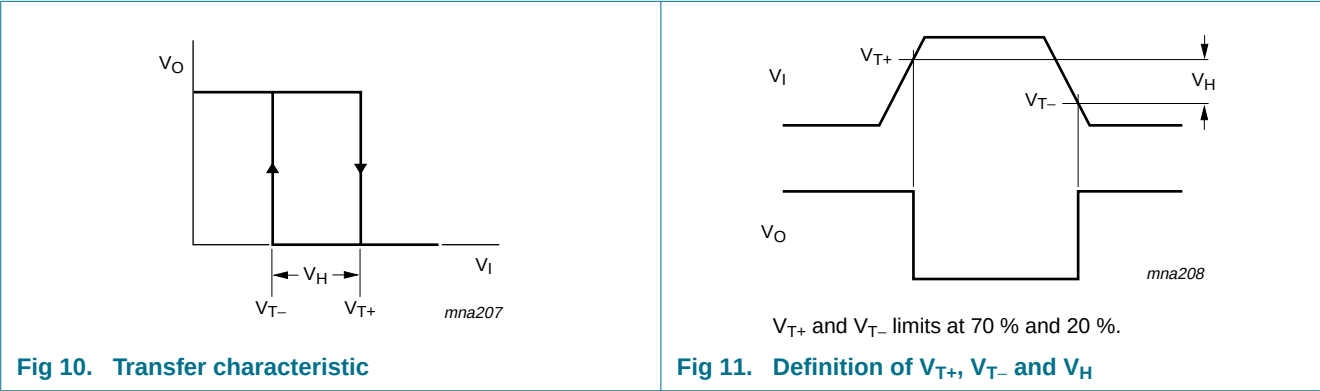


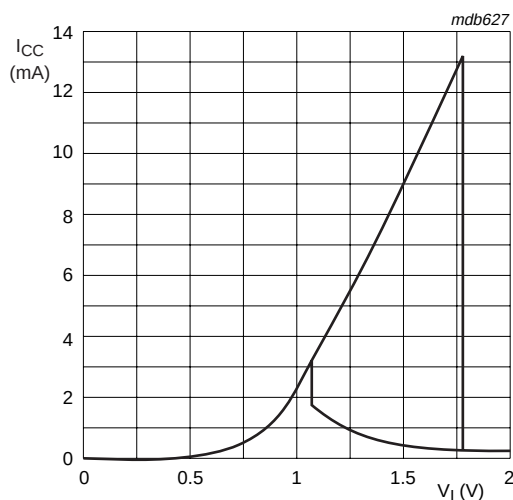
Table 11. Test data

| Supply voltage   | Input           |                                 | Load           |                | V <sub>EXT</sub>                    |
|------------------|-----------------|---------------------------------|----------------|----------------|-------------------------------------|
| V <sub>CC</sub>  | V <sub>I</sub>  | t <sub>r</sub> = t <sub>f</sub> | C <sub>L</sub> | R <sub>L</sub> | t <sub>PLH</sub> , t <sub>PHL</sub> |
| 1.65 V to 1.95 V | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF          | 1 kΩ           | open                                |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF          | 500 Ω          | open                                |
| 2.7 V            | 2.7 V           | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | open                                |
| 3.0 V to 3.6 V   | 2.7 V           | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | open                                |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | open                                |

14. Waveforms transfer characteristics







$V_{CC} = 3.0 \text{ V}$

Fig 12. Typical transfer characteristics

## 15. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$P_{\text{add}} = f_i \times (t_r \times \Delta I_{CC(\text{AV})} + t_f \times \Delta I_{CC(\text{AV})}) \times V_{CC} \text{ where:}$$

$P_{\text{add}}$  = additional power dissipation ( $\mu\text{W}$ );

$f_i$  = input frequency (MHz);

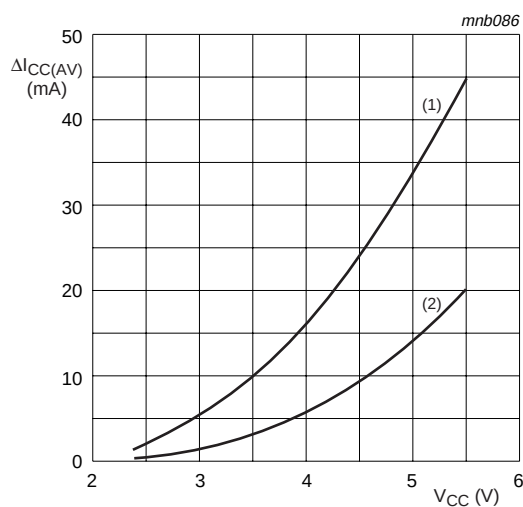
$t_r$  = input rise time (ns); 10 % to 90 %;

$t_f$  = input fall time (ns); 90 % to 10 %;

$\Delta I_{CC(\text{AV})}$  = average additional supply current ( $\mu\text{A}$ ).

$\Delta I_{CC(\text{AV})}$  differs with positive or negative input transitions, as shown in [Figure 13](#).

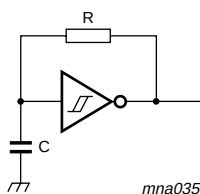
An example of a relaxation circuit using the 74LVC3G14 is shown in [Figure 14](#).



Linear change of V<sub>I</sub> between 0.8 V to 2.0 V. All values given are typical unless otherwise specified.

- (1) Positive-going edge.
- (2) Negative-going edge.

**Fig 13.** ΔI<sub>CC(AV)</sub> as a function of V<sub>CC</sub>



$$f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$$

**Fig 14.** Relaxation oscillator

16. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2

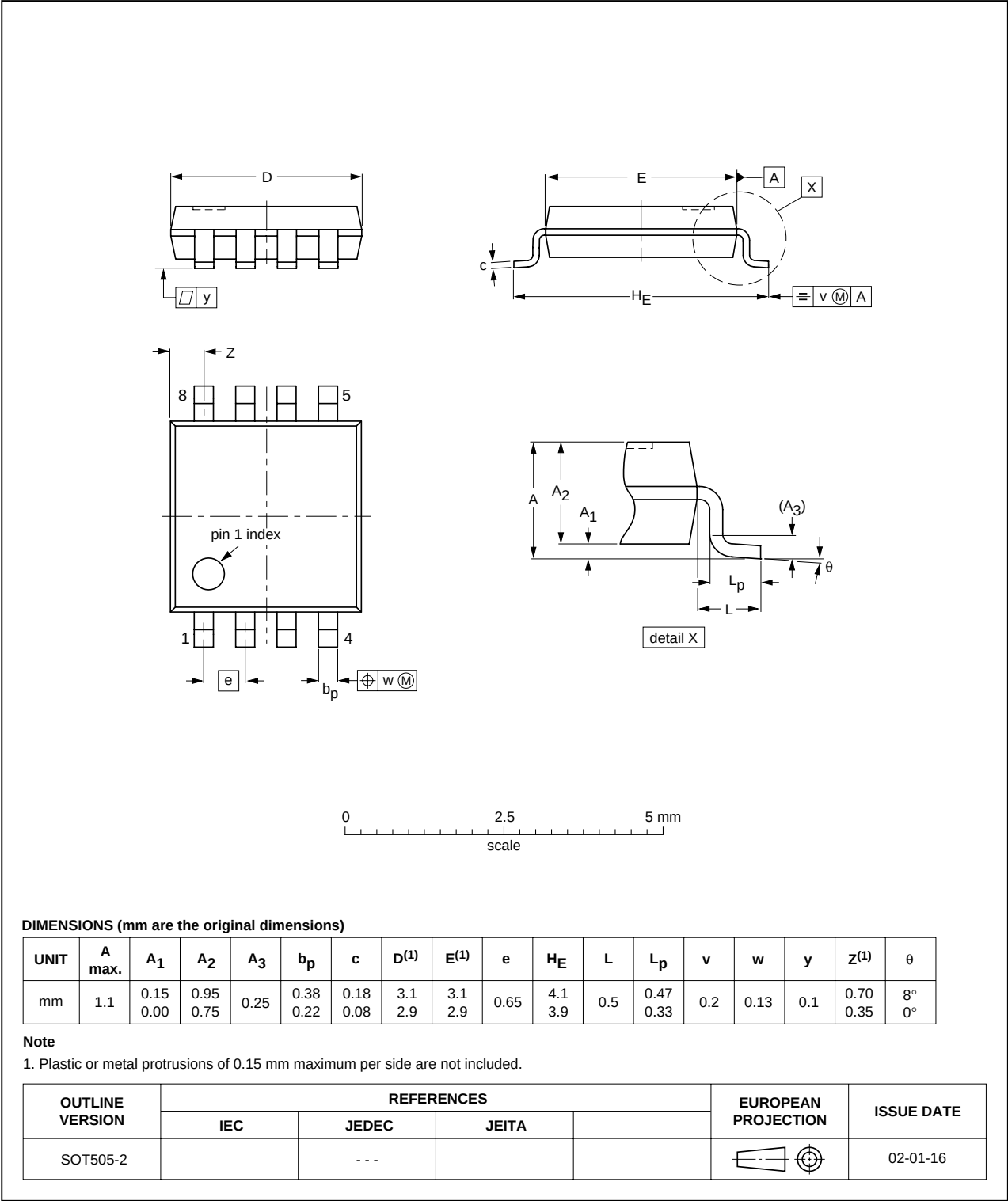


Fig 15. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

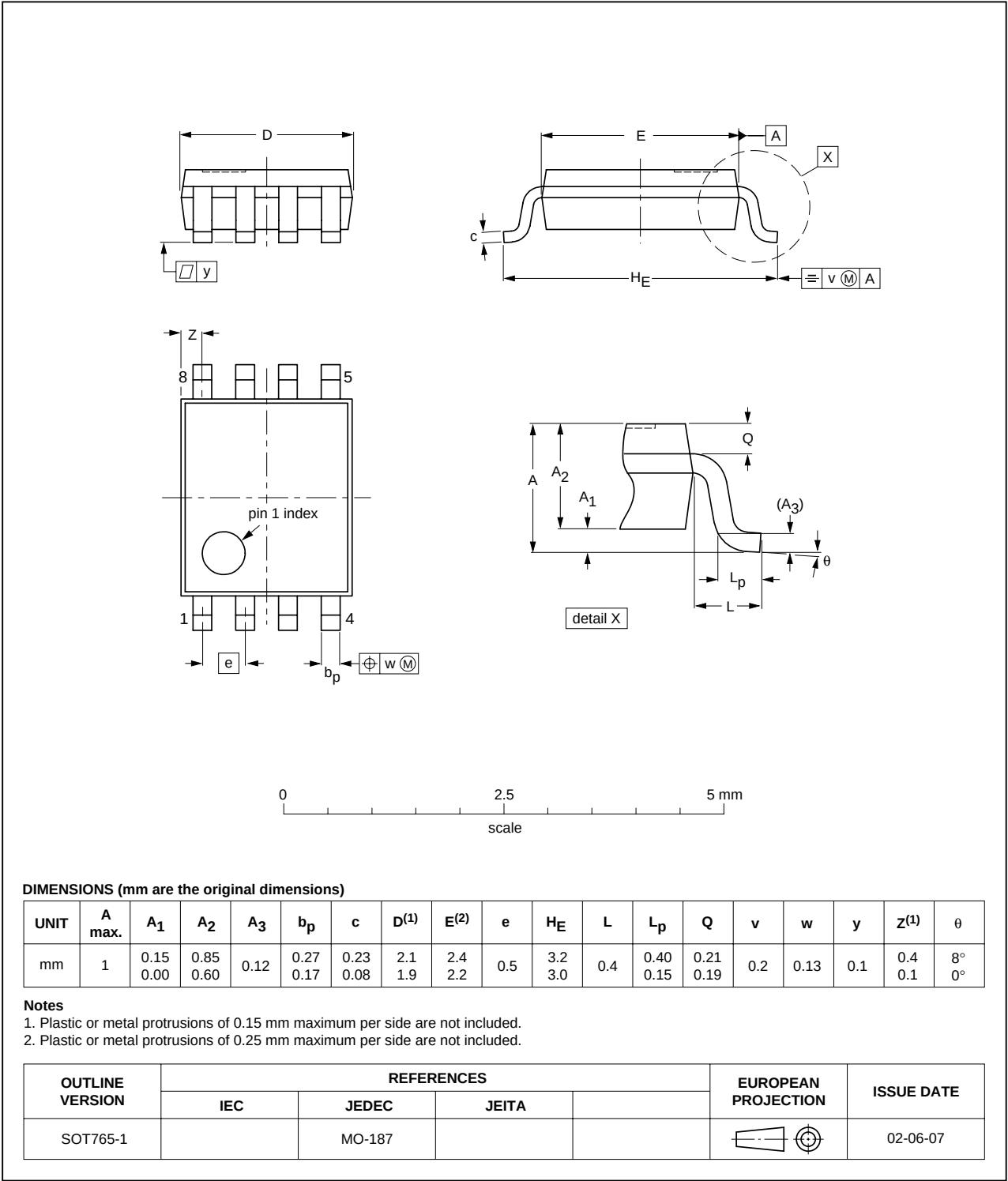


Fig 16. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

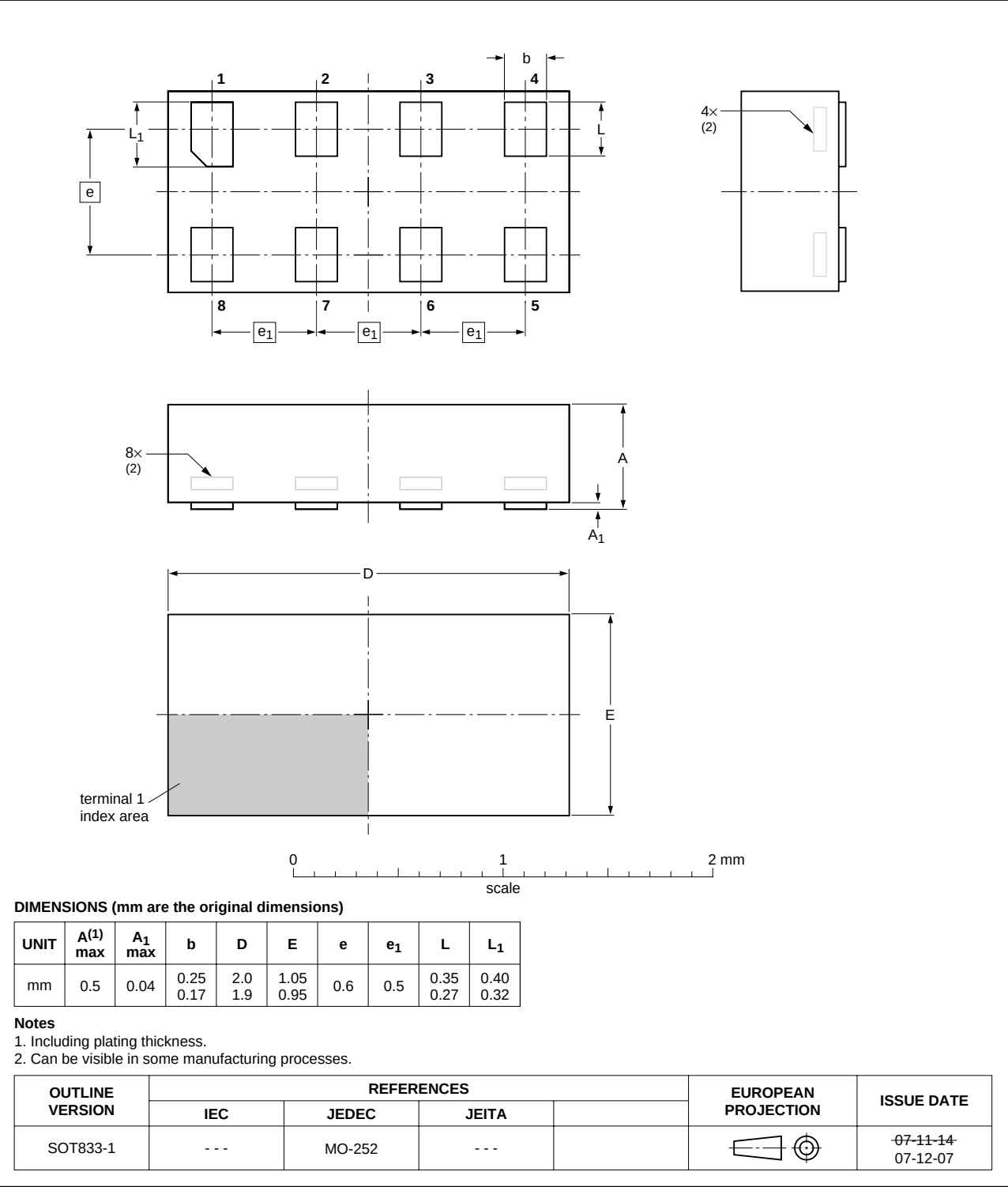


Fig 17. Package outline SOT833-1 (XSON8)

XSON8U: plastic extremely thin small outline package; no leads;  
8 terminals; UTLP based; body 3 x 2 x 0.5 mm

SOT996-2

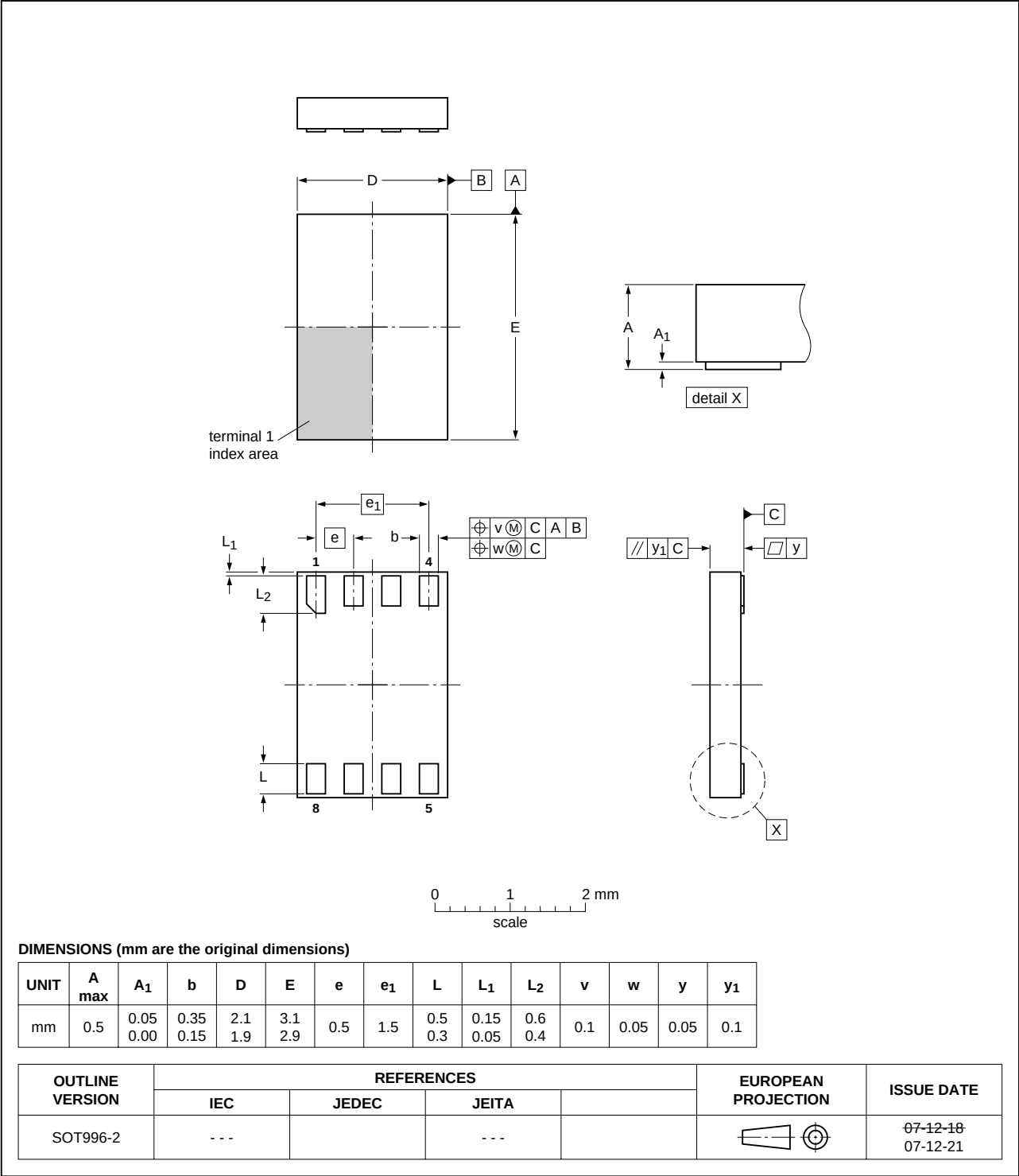


Fig 18. Package outline SOT996-2 (XSON8U)

XQFN8U: plastic extremely thin quad flat package; no leads;  
8 terminals; UTLP based; body 1.6 x 1.6 x 0.5 mm

SOT902-1

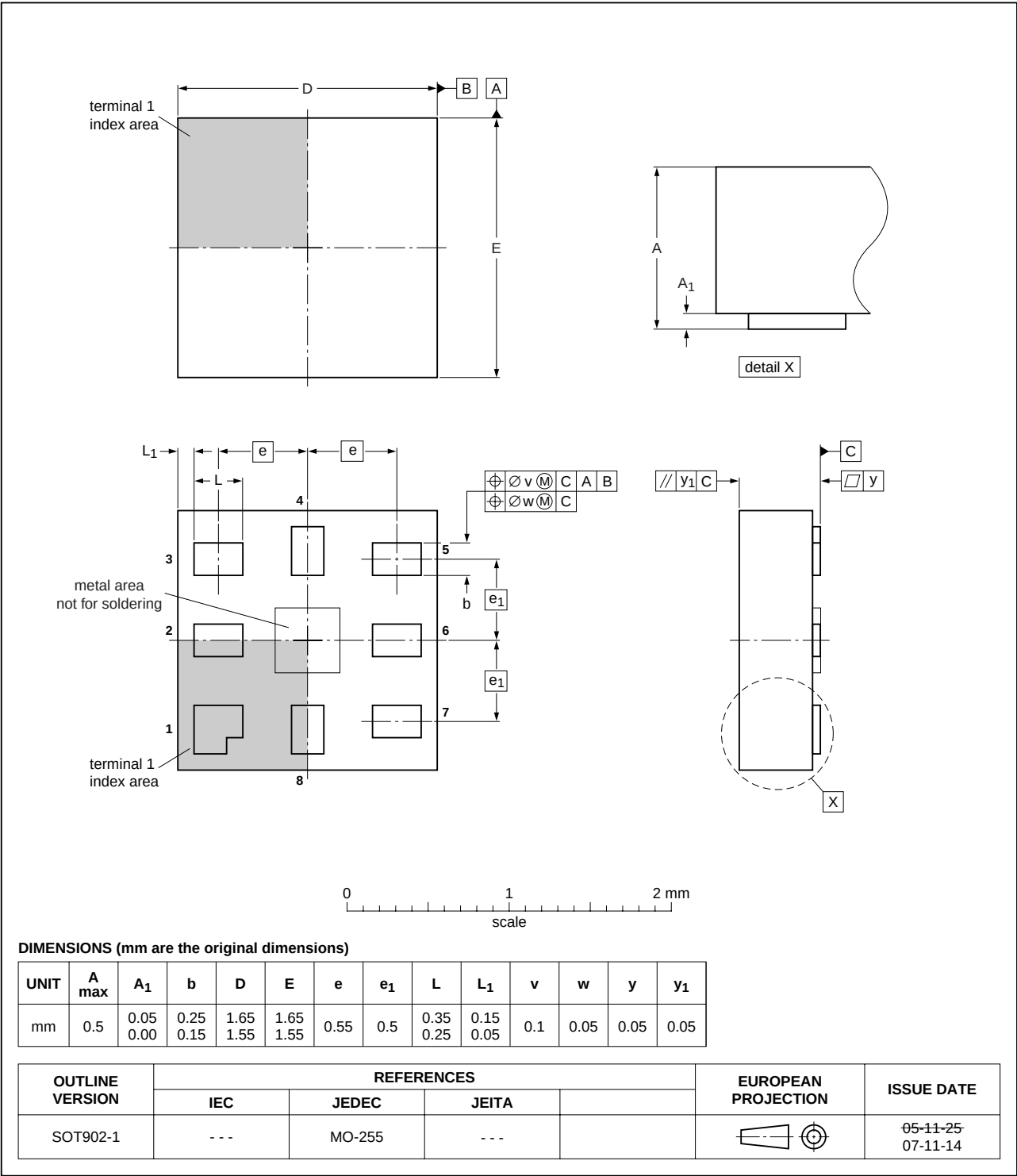


Fig 19. Package outline SOT902-1 (XQFN8U)

## 17. Abbreviations

**Table 12. Abbreviations**

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |
| UTLP    | Ultra-Thin Leadless Package             |

## 18. Revision history

**Table 13. Revision history**

| Document ID    | Release date                                                                                                                                                                         | Data sheet status  | Change notice | Supersedes  |
|----------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|-------------|
| 74LVC3G14_7    | 20080612                                                                                                                                                                             | Product data sheet | -             | 74LVC3G14_6 |
| Modifications: | <ul style="list-style-type: none"><li>• <a href="#">Section 9</a>: derating factor for TSSOP8 package corrected.</li><li>• Added type number 74LVC3G14GD (XSON8U package).</li></ul> |                    |               |             |
| 74LVC3G14_6    | 20080207                                                                                                                                                                             | Product data sheet | -             | 74LVC3G14_5 |
| 74LVC3G14_5    | 20071005                                                                                                                                                                             | Product data sheet | -             | 74LVC3G14_4 |
| 74LVC3G14_4    | 20070314                                                                                                                                                                             | Product data sheet | -             | 74LVC3G14_3 |
| 74LVC3G14_3    | 20050131                                                                                                                                                                             | Product data sheet | -             | 74LVC3G14_2 |
| 74LVC3G14_2    | 20041027                                                                                                                                                                             | Product data sheet | -             | 74LVC3G14_1 |
| 74LVC3G14_1    | 20040510                                                                                                                                                                             | Product data sheet | -             | -           |



## 19. Legal information

### 19.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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